NSN 5962-01-178-2776

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-178-2776

view Orilline at https://derobasegroup.com/histi/0302-01-170-2770
Body Length:
1.290 inches
Body Width:
Between 0.500 inches and 0.610 inches
Body Height:
Between 0.150 inches and 0.210 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-55.0/+150.0 degrees celsius
End Application:
Paveway iii Illgb
Features Provided:
Electrostatic sensitive and programmed and monolithic and w/active pull-up and 3-state output
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Current Rating Per Characteristic:
185.00 milliamperes reverse current, dc absolute and 100.00 milliamperes reverse current, dc
Product Name:
Microcircuit, digital, programed operational flight prom
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source and -1.5 volts input and 5.5 volts input
Time Rating Per Chacteristic:
100.00 nanoseconds access
Memory Device Type:
Prom
Memory Capacity:
2 k x 8
Special Features:
This programed microcircuit is made from pn m38510/21002bja and programed iaw drw 2793858 cage 9621
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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